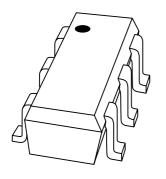
## **DISCRETE SEMICONDUCTORS**

# DATA SHEET



# **PUMH18** NPN/NPN resistor-equipped transistors; R1 = 4.7 kΩ, R2 = 10 kΩ

**Product specification** 

2003 Oct 16





# NPN/NPN resistor-equipped transistors; R1 = 4.7 k $\Omega$ , R2 = 10 k $\Omega$

**PUMH18** 

 $k\Omega$ 

#### **FEATURES**

- Built-in bias resistors
- · Simplified circuit design
- Reduction of component count
- · Reduced pick and place costs.

#### **APPLICATION**

- · Low current peripheral driver
- Replacement of general purpose transistors in digital applications
- · Control of IC inputs.

SYMBOL	PARAMETER	TYP.	MAX.	UNIT
V <sub>CEO</sub>	collector-emitter voltage	_	50	٧
Io	output current (DC)	_	100	mA
TR1	NPN	_	_	
TR2	NPN	_	_	
R1	bias resistor	4.7	_	kΩ

10

**QUICK REFERENCE DATA** 

bias resistor

#### **DESCRIPTION**

NPN/NPN resistor-equipped transistors (see "Simplified outline, symbol and pinning" for package details).

#### **PRODUCT OVERVIEW**

TYPE NUMBER	PAC	KAGE	MARKING CODE <sup>(1)</sup>	PNP/PNP
TIPE NOWIBER	PHILIPS	EIAJ	MARKING CODE	COMPLEMENT
PUMH18	SOT363	SC-88	H5*	PUMB18

R2

#### Note

- 1. \* = p: made in Hong Kong.
  - \* = t: made in Malaysia.
  - \* = W: made in China.

#### SIMPLIFIED OUTLINE, SYMBOL AND PINNING

TYPE NUMBER	SIMPLIFIED OUTLINE AND SYMBOL	PINNING	
TIPE NOMBER	SIMIFLIFIED OUTLINE AND STMBOL	PIN	DESCRIPTION
PUMH18	6 5 4	1	emitter TR1
	6 5 4	2	base TR1
	R1 R2	3	collector TR2
	TR2	4	emitter TR2
	TR1 R2 R1		base TR2
			collector TR1
	Top view MAMAZE		
	MAM478		

Philips Semiconductors Product specification

## NPN/NPN resistor-equipped transistors; R1 = 4.7 k $\Omega$ , R2 = 10 k $\Omega$

PUMH18

#### **ORDERING INFORMATION**

TYPE NUMBER		PACKAGE	
I TPE NUMBER	NAME	DESCRIPTION	VERSION
PUMH18	_	plastic surface mounted package; 6 leads	SOT363

#### **LIMITING VALUES**

In accordance with the Absolute Maximum System (IEC 60134).

SYMBOL	PARAMETER	CONDITION	MIN.	MAX.	UNIT		
Per transist	Per transistor						
V <sub>CBO</sub>	collector-base voltage	open emitter	_	50	V		
V <sub>CEO</sub>	collector-emitter voltage	open base	_	50	V		
V <sub>EBO</sub>	emitter-base voltage	open collector	_	10	V		
Vi	input voltage						
	positive		_	+20	V		
	negative		_	-7	V		
Io	output current (DC)		_	100	mA		
I <sub>CM</sub>	peak collector current		_	100	mA		
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C; note 1	_	200	mW		
T <sub>stg</sub>	storage temperature		-65	+150	°C		
Tj	junction temperature		_	150	°C		
T <sub>amb</sub>	operating ambient temperature		-65	+150	°C		
Per device	•	•	•	•	•		
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> ≤ 25 °C; note 1	_	300	mW		

#### Note

1. Device mounted on an FR4 printed-circuit board, single-sided copper, standard footprint.

#### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER CONDITIONS		VALUE	UNIT
Per transist	or			
R <sub>th j-a</sub>	thermal resistance from junction to ambient	625	K/W	
Per device				
R <sub>th j-a</sub>	thermal resistance from junction to ambient	T <sub>amb</sub> ≤ 25 °C; note 1	416	K/W

#### Note

1. Device mounted on an FR4 printed-circuit board, single-sided copper, standard footprint.

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# NPN/NPN resistor-equipped transistors; R1 = 4.7 k $\Omega$ , R2 = 10 k $\Omega$

PUMH18

#### **CHARACTERISTICS**

 $T_{amb}$  = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT	
Per transis	Per transistor						
I <sub>CBO</sub>	collector-base cut-off current	V <sub>CB</sub> = 50 V; I <sub>E</sub> = 0	_	_	100	nA	
I <sub>CEO</sub>	collector-emitter cut-off current	V <sub>CE</sub> = 30 V; I <sub>B</sub> = 0	_	_	1	μΑ	
		$V_{CE} = 30 \text{ V}; I_B = 0; T_j = 150^{\circ}\text{C}$	_	_	50	μΑ	
I <sub>EBO</sub>	emitter-base cut-off current	V <sub>EB</sub> = 5 V; I <sub>C</sub> = 0	_	_	600	μΑ	
h <sub>FE</sub>	DC current gain	V <sub>CE</sub> = 5 V; I <sub>C</sub> = 10 mA	50	_	_	_	
V <sub>CEsat</sub>	collector-emitter saturation voltage	I <sub>C</sub> = 10 mA; I <sub>B</sub> = 0.5 mA	_	_	100	mV	
V <sub>i(off)</sub>	input-off voltage	I <sub>C</sub> = 100 μA; V <sub>CE</sub> = 5 V	_	_	0.3	V	
V <sub>i(on)</sub>	input-on voltage	$I_C = 20 \text{ mA}; V_{CE} = 0.3 \text{ V}$	2.5	_	_	V	
R1	input resistor		3.3	4.7	6.1	kΩ	
R2 R1	resistor ratio		1.7	2.1	2.6	_	
C <sub>c</sub>	collector capacitance	$V_{CB} = 10 \text{ V}; I_E = i_e = 0; f = 1 \text{ MHz}$	_	_	2.5	pF	

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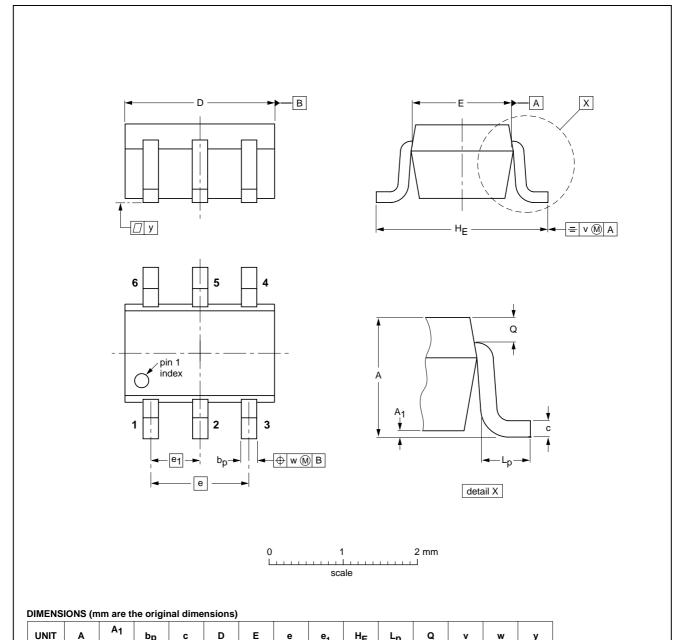
## NPN/NPN resistor-equipped transistors; $R1 = 4.7 \text{ k}\Omega$ , $R2 = 10 \text{ k}\Omega$

PUMH18

#### **PACKAGE OUTLINE**

Plastic surface mounted package; 6 leads

**SOT363** 



OUTLINE		REFERENCES EUROPEAN ISSUE DA			REFERENCES		ISSUE DATE
VERSION	IEC	JEDEC			ISSUE DATE		
SOT363			SC-88			97-02-28	

0.65

 $\mathsf{L}_\mathsf{p}$ 

0.45

0.15

ΗE

Q

0.25

w

0.2

у

0.1

2003 Oct 16 5

bp

0.30

0.20

0.25

0.10

2.2

max

0.1

mm

Ε

1.35

1.15

1.3

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## NPN/NPN resistor-equipped transistors; R1 = 4.7 k $\Omega$ , R2 = 10 k $\Omega$

PUMH18

#### **DATA SHEET STATUS**

LEVEL	DATA SHEET STATUS <sup>(1)</sup>	PRODUCT STATUS(2)(3)	DEFINITION
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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- 3. For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

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